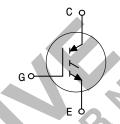
## Designer's™ Data Sheet

# **Insulated Gate Bipolar Transistor**

### N-Channel Enhancement-Mode Silicon Gate

This Insulated Gate Bipolar Transistor (IGBT) uses an advanced termination scheme to provide an enhanced and reliable high voltage—blocking capability. Short circuit rated IGBT's are specifically suited for applications requiring a guaranteed short circuit withstand time such as Motor Control Drives. Fast switching characteristics result in efficient operation at high frequencies.

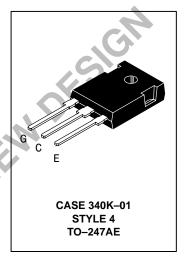
- Industry Standard High Power TO–247 Package with Isolated Mounting Hole
- High Speed E<sub>off</sub>: 150 μJ/A typical at 125°C
- High Short Circuit Capability 10 μs minimum
- Robust High Voltage Termination



### MGW12N120

Motorola Preferred Device

IGBT IN TO-247 12 A @ 90°C 20 A @ 25°C 1200 VOLTS SHORT CIRCUIT RATED



### MAXIMUM RATINGS (T<sub>.1</sub> = 25°C unless otherwise noted)

Rating	Symbol	Value	Unit
Collector–Emitter Voltage	V <sub>CES</sub>	1200	Vdc
Collector–Gate Voltage ( $R_{GE} = 1.0 \text{ M}\Omega$ )	V <sub>CGR</sub>	1200	Vdc
Gate-Emitter Voltage — Continuous	$V_{GE}$	±20	Vdc
Collector Current — Continuous @ T <sub>C</sub> = 25°C — Continuous @ T <sub>C</sub> = 90°C — Repetitive Pulsed Current (1)	I <sub>C25</sub> I <sub>C90</sub> I <sub>CM</sub>	20 12 40	Adc Apk
Total Power Dissipation @ T <sub>C</sub> = 25°C Derate above 25°C	P <sub>D</sub>	125 0.98	Watts W/°C
Operating and Storage Junction Temperature Range	T <sub>J</sub> , T <sub>stg</sub>	-55 to 150	°C
Short Circuit Withstand Time $(V_{CC}=720\ Vdc,\ V_{GE}=15\ Vdc,\ T_J=125^{\circ}C,\ R_G=20\ \Omega)$	t <sub>sc</sub>	10	μS
Thermal Resistance — Junction to Case – IGBT — Junction to Ambient	R <sub>θJC</sub> R <sub>θJA</sub>	1.0 45	°C/W
Maximum Lead Temperature for Soldering Purposes, 1/8" from case for 5 seconds	TL	260	°C
Mounting Torque, 6–32 or M3 screw	10 lbf•in (1.13 N•m)		

<sup>(1)</sup> Pulse width is limited by maximum junction temperature. Repetitive rating.

**Designer's Data for "Worst Case" Conditions** — The Designer's Data Sheet permits the design of most circuits entirely from the information presented. SOA Limit curves — representing boundaries on device characteristics — are given to facilitate "worst case" design.

Designer's is a trademark of Motorola, Inc.

Preferred devices are Motorola recommended choices for future use and best overall value.

REV<sub>3</sub>



### MGW12N120

### **ELECTRICAL CHARACTERISTICS** ( $T_J = 25^{\circ}C$ unless otherwise noted)

Cha	racteristic	Symbol	Min	Тур	Max	Unit
OFF CHARACTERISTICS						
Collector–to–Emitter Breakdown Vo $(V_{GE}=0\ Vdc,\ I_{C}=25\ \mu Adc)$ Temperature Coefficient (Positive	·	V <sub>(BR)CES</sub>	1200 —	— 870	_	Vdc mV/°C
Emitter-to-Collector Breakdown Voltage (V <sub>GE</sub> = 0 Vdc, I <sub>EC</sub> = 100 mAdc)		V <sub>(BR)ECS</sub>	25	_	_	Vdc
Zero Gate Voltage Collector Curren ( $V_{CE} = 1200 \text{ Vdc}$ , $V_{GE} = 0 \text{ Vdc}$ ) ( $V_{CE} = 1200 \text{ Vdc}$ , $V_{GE} = 0 \text{ Vdc}$ , T		ICES	_ _		100 2500	μAdc
Gate–Body Leakage Current (V <sub>GE</sub> = ± 20 Vdc, V <sub>CE</sub> = 0 Vdc)		I <sub>GES</sub>	_	_	250	nAdc
ON CHARACTERISTICS (1)						
Collector-to-Emitter On-State Volt ( $V_{GE}$ = 15 Vdc, $I_{C}$ = 5.0 Adc) ( $V_{GE}$ = 15 Vdc, $I_{C}$ = 5.0 Adc, $T_{J}$ = ( $V_{GE}$ = 15 Vdc, $I_{C}$ = 10 Adc)		V <sub>CE(on)</sub>	_ _ _	2.51 2.36 3.5	3.37	Vdc
Gate Threshold Voltage $(V_{CE} = V_{GE}, I_{C} = 1.0 \text{ mAdc})$ Threshold Temperature Coefficie	nt (Negative)	V <sub>GE(th)</sub>	4.0 —	6.0 10	8.0	Vdc mV/°C
Forward Transconductance (V <sub>CE</sub> =	10 Vdc, I <sub>C</sub> = 10 Adc)	9 <sub>fe</sub>	\$	12	_	Mhos
DYNAMIC CHARACTERISTICS						
Input Capacitance		C <sub>ies</sub>	7	930	_	pF
Output Capacitance	$(V_{CE} = 25 \text{ Vdc}, V_{GE} = 0 \text{ Vdc}, f = 1.0 \text{ MHz})$	C <sub>oes</sub>	_	126	_	
Transfer Capacitance		C <sub>res</sub>	_	16	_	
SWITCHING CHARACTERISTICS (	1)					
Turn-On Delay Time		t <sub>d(on)</sub>	_	74	_	ns
Rise Time	$(V_{CC} = 720 \text{ Vdc}, I_{C} = 10 \text{ Adc},$	t <sub>r</sub>	_	83	_	
Turn-Off Delay Time	$V_{GE} = 15 \text{ Vdc}, L = 300 \mu H$ $R_{G} = 20 \Omega$ )	t <sub>d(off)</sub>	_	76	_	
Fall Time	Energy losses include "tail"	t <sub>f</sub>	_	231	_	
Turn-Off Switching Loss		E <sub>off</sub>	_	0.55	1.33	mJ
Turn-On Delay Time		t <sub>d(on)</sub>	_	66	_	ns
Rise Time	$(V_{CC} = 720 \text{ Vdc}, I_C = 10 \text{ Adc},$	t <sub>r</sub>	_	87	_	
Turn-Off Delay Time	$V_{GE} = 15 \text{ Vdc}, L = 300 \mu\text{H}$ $R_G = 20 \Omega, T_J = 125^{\circ}\text{C}$	t <sub>d(off)</sub>	_	120	_	
Fall Time	Energy losses include "tail"	t <sub>f</sub>	_	575	_	
Turn-Off Switching Loss	//0	E <sub>off</sub>	_	1.49	_	mJ
Gate Charge	0	Q <sub>T</sub>	_	31	_	nC
	(V <sub>CC</sub> = 720 Vdc, I <sub>C</sub> = 10 Adc, V <sub>GE</sub> = 15 Vdc)	Q <sub>1</sub>	_	13	_	
	*GE = 10 *GO)	Q <sub>2</sub>	_	14	_	
NTERNAL PACKAGE INDUCTANC	E					
Internal Emitter Inductance (Measured from the emitter lead	0.25" from package to emitter bond pad)	L <sub>E</sub>		13		nH

(1) Pulse Test: Pulse Width  $\leq$  300  $\mu$ s, Duty Cycle  $\leq$  2%.

### TYPICAL ELECTRICAL CHARACTERISTICS

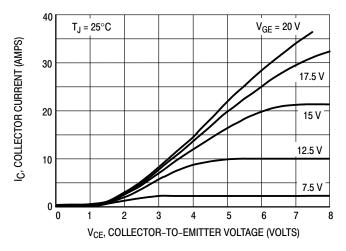


Figure 1. Output Characteristics

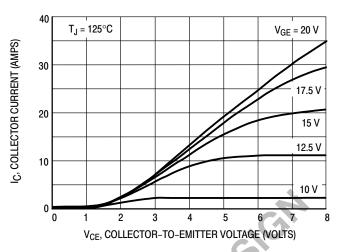
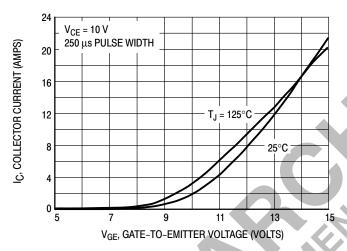


Figure 2. Output Characteristics



**Figure 3. Transfer Characteristics** 

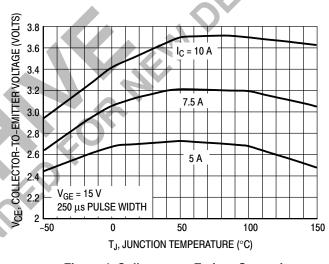


Figure 4. Collector-to-Emitter Saturation Voltage versus Junction Temperature

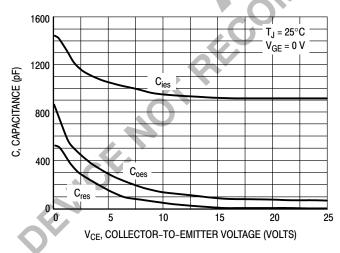


Figure 5. Capacitance Variation

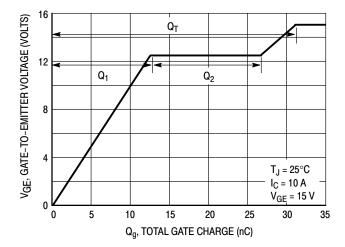


Figure 6. Gate-to-Emitter Voltage versus
Total Charge

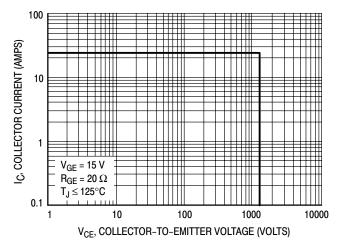


Figure 7. Reverse Biased Safe Operating Area

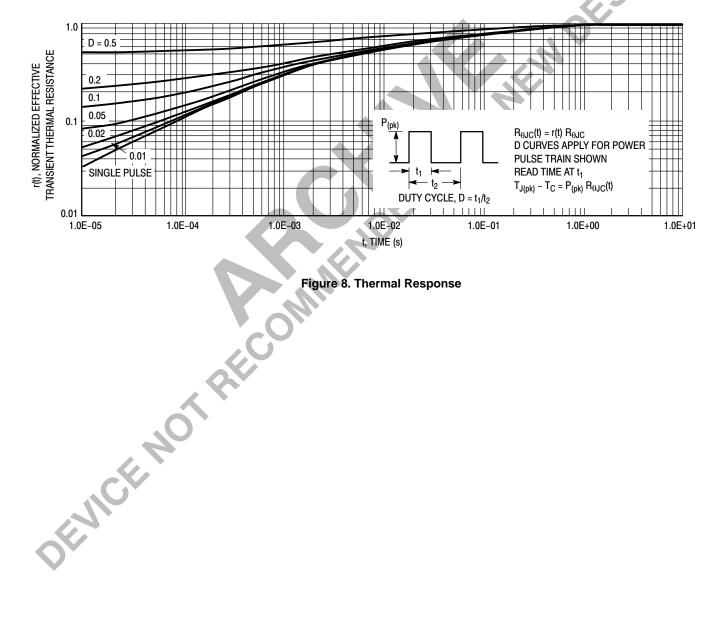
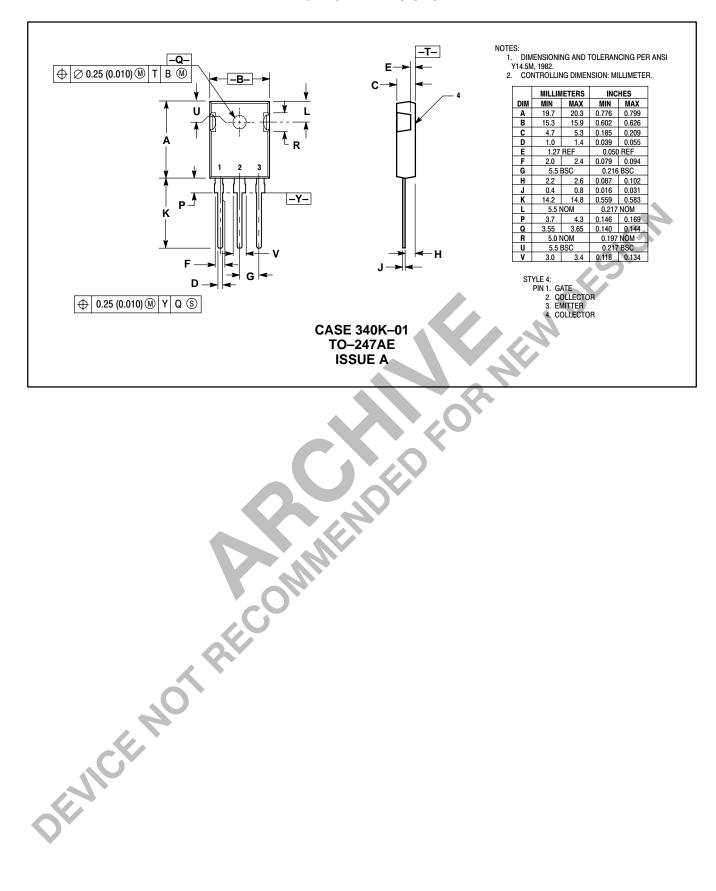


Figure 8. Thermal Response

#### PACKAGE DIMENSIONS





Motorola reserves the right to make changes without further notice to any products herein. Motorola makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does Motorola assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation consequential or incidental damages. "Typical" parameters which may be provided in Motorola data sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. Motorola does not convey any license under its patent rights nor the rights of others. Motorola products are not designed, intended, or authorized for use as components in systems intended for surgical implant into the body, or other applications intended to support or sustain life, or for any other application in which the failure of the Motorola product could create a situation where personal injury or death may occur. Should Buyer purchase or use Motorola products for any such unintended or unauthorized application, Buyer shall indemnify and hold Motorola and its officers, employees, subsidiaries, affiliates, and distributors harmless against all claims, costs, damages, and expenses, and reasonable attorney fees arising out of, directly or indirectly, any claim of personal injury or death associated with such unintended or unauthorized use, even if such claim alleges that Motorola was negligent regarding the design or manufacture of the part. Motorola and are registered trademarks of Motorola, Inc. Motorola, Inc. is an Equal Opportunity/Affirmative Action Employer.

Mfax is a trademark of Motorola, Inc.

#### How to reach us:

**USA/EUROPE/Locations Not Listed**: Motorola Literature Distribution; P.O. Box 5405, Denver, Colorado 80217. 1–303–675–2140 or 1–800–441–2447

JAPAN: Nippon Motorola Ltd.: SPD, Strategic Planning Office, 141, 4–32–1 Nishi-Gotanda, Shagawa-ku, Tokyo, Japan. 03–5487–8488

#### Customer Focus Center: 1-800-521-6274

Mfax™: RMFAX0@email.sps.mot.com - TOUCHTONE 1-602-244-6609

Motorola Fax Back System - US & Canada ONLY 1-800-774-1848

- http://sps.motorola.com/mfax/

ASIA/PACIFIC: Motorola Semiconductors H.K. Ltd.; 8B Tai Ping Industrial Park,

LY 1–800–774–1848 51 Ting Kok Road, Tai Po, N.T., Hong Kong. 852–26629298

HOME PAGE: http://motorola.com/sps/



MGW12N120/D